

Data Sheet

February 27, 2009

FN6742.0

Filterless High Efficiency 1.5W Class D Mono Amplifier

intercil

The ISL99201 is a fully integrated high efficiency class-D mono amplifier. It is designed to maximize performance for mobile phone applications. The application circuit requires a minimum requirement of external components and operates from a 2.4V to 5.5V input supply. It is capable of delivering 1.4W of continuous output power with less than 1% THD+N driving a 8 Ω load from a 5V supply.

The ISL99201 features a high-efficiency, low-noise modulation scheme. It operates with 86% efficiency at 400mW into 8 Ω and has a signal-to-noise ratio (SNR) that is better than 95dB. The ISL99201 has a micro-power shutdown mode with a typical shutdown current of 200nA. Shutdown is enabled by applying a logic low to the $\overline{\text{SD}}$ pin.

The architecture of the devices allows it to achieve very low level of pop-and-click. This minimizes voltage glitches at the output during turn-on and turn-off, thus reducing audible noise on activation and deactivation.

The fully differential input of the ISL99201 provides excellent rejection of common mode noise on the input typically 75dB. EMI suppression is achieved by SRC (Slew Rate Control).

The ISL99201 oscillator can be synchronized to an external clock through the SYNC input, allowing the switching frequency to be externally defined. The SYNC input also allows multiple ISL99201 to be cascaded and frequency locked; minimizing interference due to clock intermodulation. SYNC is available only in DFN version.

The ISL99201 also has excellent rejection of power supply noise, including noise caused by GSM transmission bursts and RF rectification. PSRR is typically 75dB at 217Hz. There will be 4 versions of the part; they will consist of three fixed gain settings (6dB, 9.6dB, 12dB) and one user programmable gain setting (need external resistors).

The ISL99201 has built-in thermal shutdown and output short-circuit protection.

Features

- Filterless Class D with Efficiency > 86% at 400mW
- Click-Pop Suppression
- Slew Rate Control
- Spread Spectrum Switching
- Optional SYNC Pin for Master/Slave Operation Without Interface (Only in TDFN)
- 1.4W into 8Ω with Less than 1% THD+N
- 2.4V to 5.5V Single Supply Voltage
- Built-in Resistors to Reduce Board Component Count
- Only One External Component Required (Fixed Gain Mode)
- Short Circuit and Thermal Protection
- Gain Programmable 6dB, 9.6dB, 12dB and User Programmable
- Pb-Free (RoHS compliant)

Applications

- Mobile Phones
- MP3 Players
- Portable Gaming
- Portable Electronics
- Educational Toys

Ordering Information

PART NUMBER	PART MARKING	GAIN SETTING (dB)	TEMP. RANGE (°C)	PACKAGE Tape & Reel (Pb-Free)	PKG. DWG. #
ISL99201IRTAZ-T (Notes 1, 2)	201A	6	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTAZ-TK (Notes 1, 2)	201A	6	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTBZ-T (Notes 1, 2)	201B	9.6	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTBZ-TK (Notes 1, 2)	201B	9.6	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTCZ-T (Notes 1, 2)	201C	12	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTCZ-TK (Notes 1, 2)	201C	12	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTDZ-T (Notes 1, 2)	201D	Prog.	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IRTDZ-TK (Notes 1, 2)	201D	Prog.	-40 to +85	8 Ld 3x3 TDFN	L8.3x3A
ISL99201IIAZ-T (Notes 1, 3, 4)	201A	6	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIAZ-TK (Notes 1, 3, 4)	201A	6	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIBZ-T (Notes 1, 3, 4)	201B	9.6	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIBZ-TK (Notes 1, 3, 4)	201B	9.6	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IICZ-T (Notes 1, 3, 4)	201C	12	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IICZ-TK (Notes 1, 3, 4)	201C	12	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIDZ-T (Notes 1, 3, 4)	201D	Prog.	-40 to +85	9 Ball WLCSP	W3x3.9C
ISL99201IIDZ-TK (Notes 1, 3, 4)	201D	Prog.	-40 to +85	9 Ball WLCSP	W3x3.9C

NOTES:

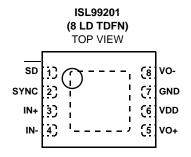
1. Please refer to TB347 for details on reel specifications.

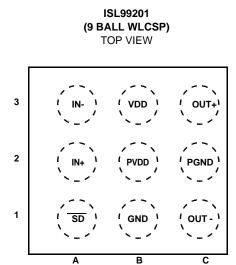
 These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

3. These Intersil Pb-free WLCSP and BGA packaged products employ special Pb-free material sets; molding compounds/die attach materials and SnAgCu - e1 solder ball terminals, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free WLCSP and BGA packaged products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

4. Please contact factory for ordering details.







Absolute Maximum Ratings (Reference to GND)

Supply Voltage		0.3V to 6V
Input Voltage	-0.3	/ to V _{DD} +0.3V

Recommended Operating Conditions

Ambient Temperature Range	40°C to +85°C
Operating Supply Voltage (V _{DD} Pin)	2.4V to 5.5V

Thermal Information

Thermal Resistance (Typical Note 5)	θ _{JA} (°C/W)
WLCSP Package	102
TDFN Package	53
Maximum Junction Temperature (Plastic Package) -65°	C to +150°C
Maximum Storage Temperature Range65°	C to +150°C
Power Dissipation Ratings	
8 Ld 3x3 TDFN	
Derating Factor	.21.8mW/°C
Power Ratings	
$T_A = +25^{\circ}C$	
$T_A = +70^{\circ}C$	
$T_A = +85^{\circ}C$	1.4W
9 Ball WLCSP	
Derating Factor	7.5mW/°C
Power Ratings	
$T_A = +25^{\circ}C$	
$T_A = +70^{\circ}C$	
$T_A = +85^{\circ}C$	
Pb-Free Reflow Profile	ee link below
http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTE:

Electrical Specifications

5. θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.

Typical Values Are Tested at V_{DD} = 5V and the Ambient Temperature at +25°C. Parameters with MIN and/or

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Output Power	Po	R_L = 8Ω, THD = 10%, f = 1kHz, 20kHz BW, V_{DD} = 5.0V		1.4		W
		R_L = 8 Ω , THD = 10%, f = 1kHz, 20kHz BW, V_{DD} = 3.6V		0.75		W
		R_L = 8 Ω , THD = 10%, f = 1kHz, 20kHz BW, V_{DD} = 2.5V		0.4		W
		R_L = 8 Ω , THD = 1%, f = 1kHz, 20kHz BW, V_{DD} = 5.0V		1.15		W
Efficiency	η	$P_{OUT} = 1.4W, 8\Omega + 33\mu H, V_{DD} = 5.0V$		90		%
Total Harmonic Distortion + Ratio	THD+N	$P_O = 1W$ into 8Ω each channel, f = 1kHz, $V_{DD} = 5.0V$		0.05		%
		$P_O = 0.5W$ into 8Ω each channel, f = 1kHz, $V_{DD} = 3.6V$		0.05		%
		$P_O = 0.2W$ into 8Ω each channel, f = 1kHz, $V_{DD} = 3.6V$		0.09		%
Common-Mode Rejection Ratio	CMRR	V_{IC} = 0.5V to (V_{DD} - 0.8V); R_L= 8\Omega, V_{DD} = 2.5V to 5.5V		-60		dB
	CMRR _{GSM}	$V_{CM} = 2.5V \pm 1V_{P-P}$ at 217Hz, R _L = 8 Ω		-60		dB
Average Switching Frequency	f _{sw}	V _{DD} = 5V	300	375	450	kHz
Differential Output Offset Voltage	V _{OOS}	G = 6dB; 9.6dB; 12dB; 28dB.		0.2	5.0	mV
POWER SUPPLY						
Supply Voltage Range	V _{DD}		2.4		5.5	V
Power Supply Rejection Ratio	PSRR	V _{DD} = 2.5V to 5.0V		-65		dB
	PSRR _{GSM}	$V_{RIPPLT} = 100 mV_{RMS}$ at 217Hz (Input AC-Coupled with 2µF capacitor)		-65		dB

Electrical Specifications

Typical Values Are Tested at V_{DD} = 5V and the Ambient Temperature at +25°C. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested. (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Supply Current	I _{IN}	$V_{IN} = 0V$, No load, $V_{DD} = 5V$		3.9		mA
		$V_{IN} = 0V$, No load, $V_{DD} = 3.6V$		3.2	3.75	mA
		$V_{IN} = 0V, 8\Omega + 33\mu H, V_{DD} = 5V$		3.9		mA
		$V_{IN} = 0V, 8\Omega + 33\mu H, V_{DD} = 3.6V$		3.8		mA
	I <u>SD</u> (Note 6)	SD = GND		0.2	0.4	μA
GAIN CONTROL						
Closed-Loop Gain		D version user program (Max Gain, Ri = 0Ω)	27.5	28.5	29.5	dB
		A version	5.7	6	6.3	dB
		B version	9.2	9.6	10	dB
		C version	11.5	12	12.5	dB
Differential Input Impedance	Z _{IN}	$\overline{SD} = V_{DD}$, A version		70		kΩ
		$\overline{SD} = V_{DD}$, B version		46.25		kΩ
		$\overline{SD} = V_{DD}, C \text{ version}$		35		kΩ
		$\overline{\text{SD}} = \text{V}_{\text{DD}}, \text{ D} \text{ version}, \text{ Ri} = 2.5 \text{k}\Omega$		7.5		kΩ
		SD = GND		100		kΩ
SHUTDOWN CONTROL	i					
Input Voltage High	V _{IH}			1.2		V
Input Voltage Low	V _{IL}			0.5		V
Turn-on Time	t _{WU}	$\overline{\text{SD}}$ rising edge from GND to V _{DD}		3.5		ms
Turn-off Time	t _{SD}	SD falling edge from V _{DD} to GND		5		μs
Output Impedance	Z _{OUT}	SD = GND		>100		kΩ
NOISE PERFORMANCE	1					
Output Voltage Noise	En	V_{DD} = 3.6V, f = 20Hz to 20kHz, inputs are AC grounded, A_V = 6dB, A-weighting		27		μV
		V_{DD} = 3.6V, f = 20Hz to 20kHz, inputs are AC grounded, $A_{V\ 0}$ = 6dB, no weighting		35		μV
Signal-to-Noise Ratio	SNR	P _{OUT} = 1W, R _L = 8Ω		102		dB

NOTE:

6. Limits established by Characterization and are not production tested

Pin Descriptions

SD

Shutdown Active Low. This signal is used to shut down and activate the part. It is 1.8V to 5V compatible. During shutdown, the part draws less than 100nA input current. Coming out of shutdown takes 3.5ms and going into shutdown is instantaneous.

SYNC

External clock input (available only in DFN). This pin allows the chip to be synchronized to a system clock. This helps in folding the spectral components and the switching harmonic out of band of interest. The range of SYNC frequency is from 250kHz to 800kHz.

IN+

Positive Differential Input.

IN-

Negative Differential Input.

Block Diagram (Notes *)

V_O+

Positive BTL output.

GND

Ground (Analog ground in CSP)

V_{DD}

Power Supply (Analog VDD in CSP)

V₀-

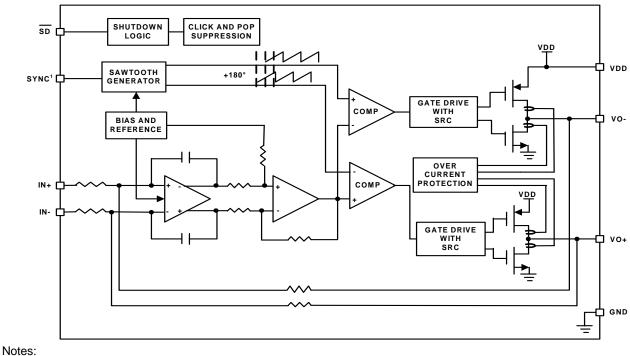
Negative BTL output

PVDD

Power Supply (CSP only)

PGND

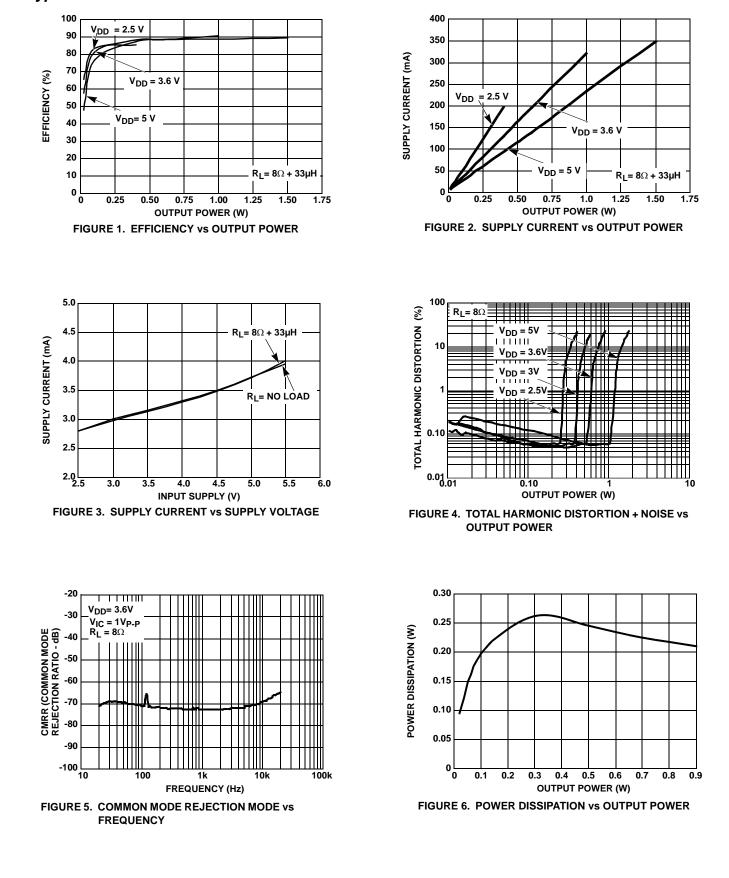
Power Ground (CSP only)



Gain = 6dB, 9.6dB, 12dB (gain setting)

 $Gain = \frac{140k\Omega}{(Ri + 5k\Omega)}; \text{ with external resistor}$ *TDFN only

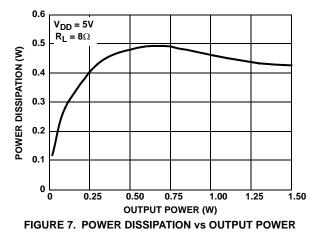
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Typical Performance Characteristics (Continued)



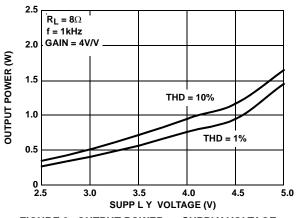
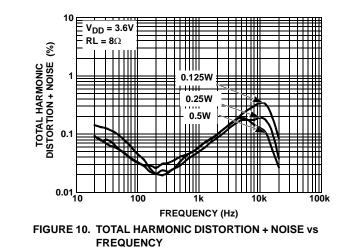
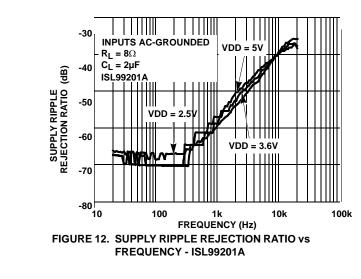
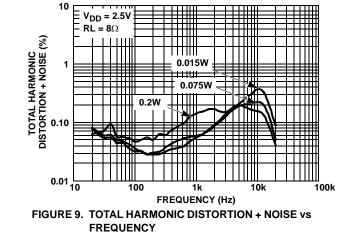
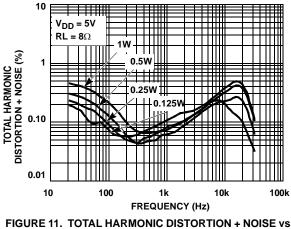


FIGURE 8. OUTPUT POWER vs SUPPLY VOLTAGE

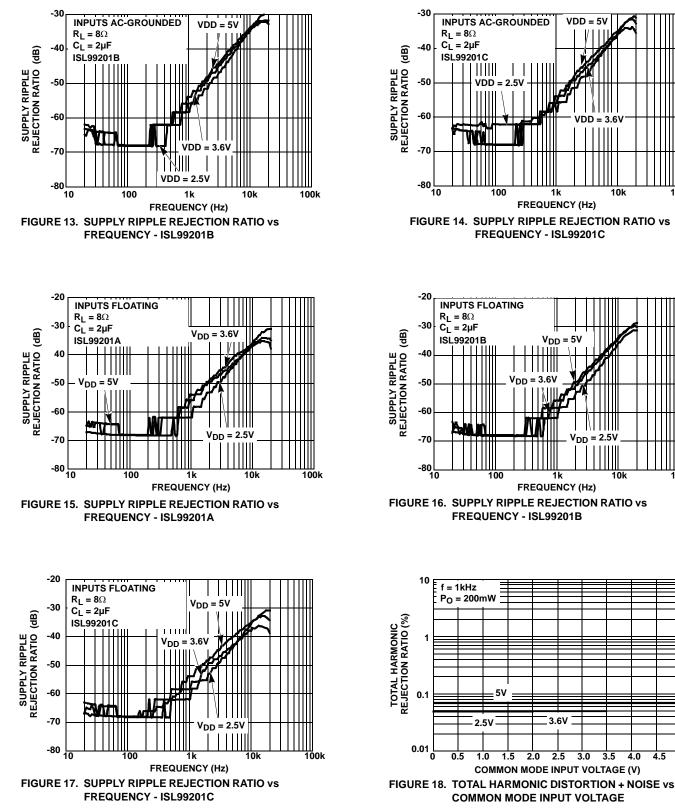








FREQUENCY



Typical Performance Characteristics (Continued)

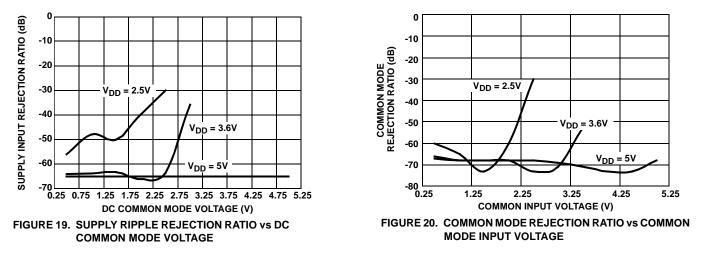
9

4.5 5.0

100k

100k

Typical Performance Characteristics (Continued)



Typical Applications

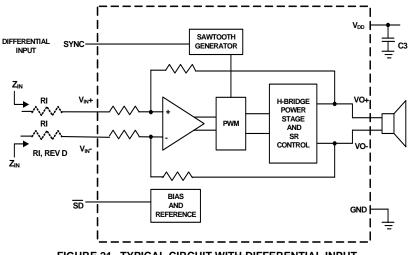


FIGURE 21. TYPICAL CIRCUIT WITH DIFFERENTIAL INPUT

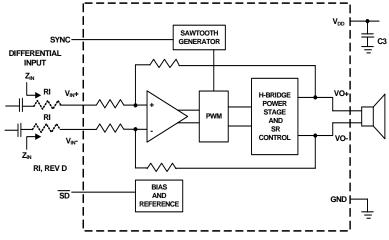


FIGURE 22. TYPICAL CIRCUIT WITH DIFFERENTIAL INPUT AND INPUT CAPACITORS

Typical Applications (Continued)

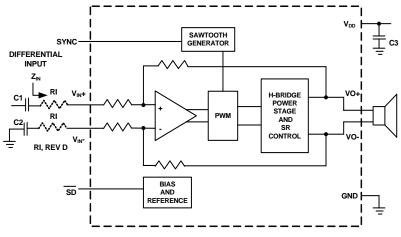
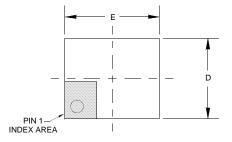
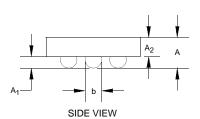


FIGURE 23. TYPICAL CIRCUIT WITH SINGLE-ENDED INPUT

Wafer Level Chip Scale Package (WLCSP 0.4mm Ball Pitch)



TOP VIEW



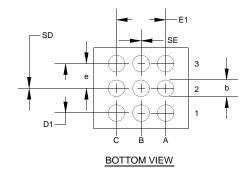
W3x3.9C

3x3 ARRAY 9 BALL WAFER LEVEL CHIP SCALE PACKAGE

SYMBOL	MILLIMETERS
А	0.445 Min, 0.495 Nom, 0.545 Max
A ₁	0.190 ±0.025
A ₂	0.305 ±0.025
b	0.270 ±0.030
D	1.315 ±0.020
D ₁	0.800 BASIC
E	1.535 ±0.020
E ₁	0.800 BASIC
е	0.400 BASIC
SD	0 BASIC
SE	0 BASIC
Ν	umber of Bumps: 9
	Rev. 0 5/08

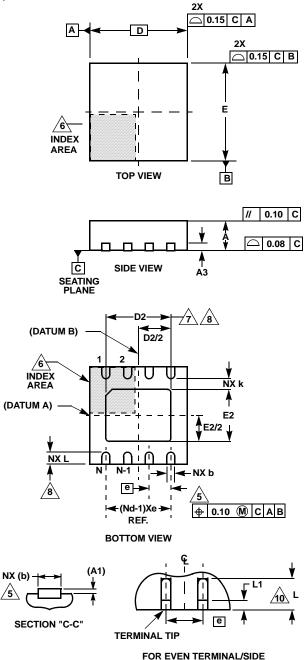
NOTES:

1. Dimensions are in Millimeters.



Thin Dual Flat No-Lead Plastic Package (TDFN)

Dual Flat No - Lead Plastic package (DFN)



L8.3x3A

8 LEAD THIN DUAL FLAT NO-LEAD PLASTIC PACKAGE

		MILLIMETER	S	
SYMBOL	MIN	NOMINAL	MAX	NOTES
А	0.70	0.75	0.80	-
A1	-	0.02	0.05	-
A3		0.20 REF		-
b	0.25	0.30	0.35	5, 8
D		3.00 BSC		
D2	2.20	2.30	2.40	7, 8, 9
E		3.00 BSC		
E2	1.40	1.50	1.60	7, 8, 9
е		0.65 BSC		
k	0.25	-	-	-
L	0.20	0.30	0.40	8
Ν	8			2
Nd		4		3
	•			Rev. 3 11/0

NOTES:

1. Dimensioning and tolerancing conform to ASME Y14.5-1994.

2. N is the number of terminals.

- 3. Nd refers to the number of terminals on D.
- 4. All dimensions are in millimeters. Angles are in degrees.
- 5. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
- 6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.
- 7. Dimensions D2 and E2 are for the exposed pads which provide improved electrical and thermal performance.
- Nominal dimensions are provided to assist with PCB Land Pattern Design efforts, see Intersil Technical Brief TB389.
- 9. Compliant to JEDEC MO-WEEC-2 except for the "L" min dimension.

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